International Rectifier

30WQ03FN

SCHOTTKY RECTIFIER

3.5 Amp

$$I_{F(AV)} = 3.5 Amp$$

 $V_R = 30 V$

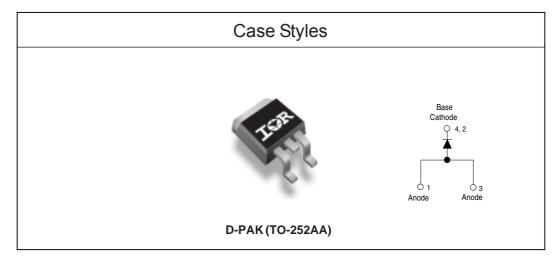
Major Ratings and Characteristics

Characteristics	Values	Units
I _{F(AV)} Rectangular waveform	3.5	А
V _{RRM}	30	V
I _{FSM} @tp=5 µs sine	535	Α
V _F @3 Apk, T _J = 125°C	0.35	V
T _J range	-40 to 150	°C

Description/ Features

The 30WQ03FN surface mount Schottky rectifier has been designed for applications requiring low forward drop and small foot prints on PC board. Typical applications are in disk drives, switching power supplies, converters, free-wheeling diodes, battery charging, and reverse battery protection.

- Popular D-PAK outline
- Small foot print, surface mountable
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability





Voltage Ratings

Part number	30WQ03FN
V _R Max. DC Reverse Voltage (V)	20
V _{RWM} Max. Working Peak Reverse Voltage (V)	30

Absolute Maximum Ratings

	Parameters	30WQ	Units	Conditions	
I _{F(AV)}	Max. Average Forward Current *See Fig. 5	3.5	А	50% duty cycle @ T _C = 134°C, rectangular wave form	
I _{FSM}	Max. Peak One Cycle Non-Repetitive	535	Α	5μs Sine or 3μs Rect. pulse	Following any rated load condition and with
	Surge Current *See Fig. 7	90	^	10ms Sine or 6ms Rect. pulse	rated V _{RRM} applied
E _{AS}	Non-Repetitive Avalanche Energy	8	mJ	T _J = 25 °C, I _{AS} = 2 Amps, L = 4 mH	
I _{AR}	Repetitive Avalanche Current	1.0	А	Current decaying linearly to zero in 1 μ sec Frequency limited by T_J max. $V_A = 1.5 \text{ x V}_R$ typical	

Electrical Specifications

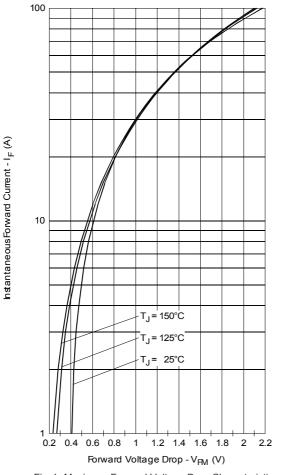
	Parameters	30WQ	Units		Conditions
V _{FM}	Max. Forward Voltage Drop	0.45	V	@ 3A	T - 25 °C
	* See Fig. 1 (1)	0.52	V	@ 6A	T _J = 25 °C
		0.35	V	@ 3A	T ₁ = 125 °C
		0.46	V	@ 6A	1 _J = 123 0
I _{RM}	Max. Reverse Leakage Currer	t 2	mA	T _J = 25 °C	V = rated V
	* See Fig. 2 (1)	50	mA	T _J = 125 °C	V _R = rated V _R
V _{F(TO}	Threshold Voltage	0.22	V	$T_J = T_J \text{ max.}$	
r _t	Forward Slope Resistance	32.86	mΩ	7	
C _T	Typical Junction Capacitance	290	pF	$V_R = 5V_{DC}$, (test signal range 100Khz to 1Mhz) 25 °C	
L _s	Typical Series Inductance	5.0	nH	Measured lead to lead 5mm from package body	
dv/dt	Max. Voltage Rate of Change	10000	V/µs	(Rated V _R)	

(1) Pulse Width < 300µs, Duty Cycle < 2%

Thermal-Mechanical Specifications

	Parameters	30WQ	Units	Conditions	
T _J	Max. Junction Temperature Range (*)	-40 to 150	°C		
T _{stg}	Max. Storage Temperature Range	-40 to 150	°C		
R _{thJC}	Max. Thermal Resistance Junction to Case	4.7	°C/W	DC operation *See Fig. 4	
wt	Approximate Weight	0.3 (0.01)	g (oz.)		
	Case Style	D-PAK		Similar to TO-252AA	
	Marking Device	30WQ03FN			

 $\frac{\binom{*}{d}}{dT_j} < \frac{1}{Rth(j-a)}$ thermal runaway condition for a diode on its own heatsink



100 T_J= 150°C 125°C Reverse Current - IR (mA) 10 100°C 75°C 50°C 0.1 25°C 0.01 0.001 5 10 15 20 30 Reverse Voltage - V_R (V)

Fig. 2-Typical Values of Reverse Current Vs. Reverse Voltage

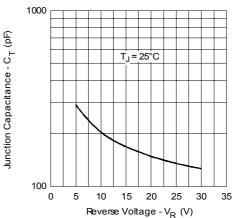


Fig. 1 - Maximum Forward Voltage Drop Characteristics

Fig. 3-Typical Junction Capacitance Vs. Reverse Voltage

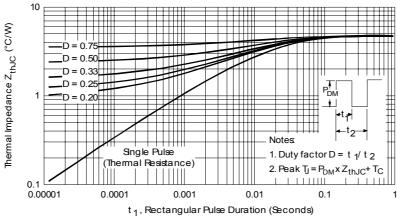


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

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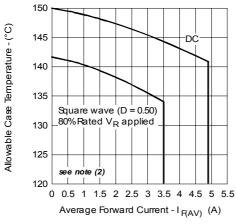


Fig. 5 - Maximum Allowable Case Temperature Vs. Average Forward Current

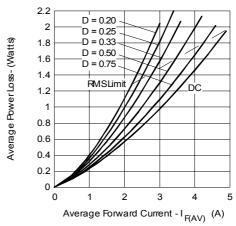


Fig. 6-Forward Power Loss Characteristics

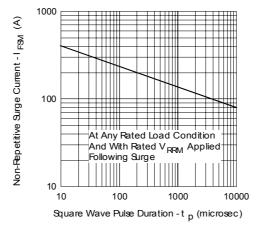
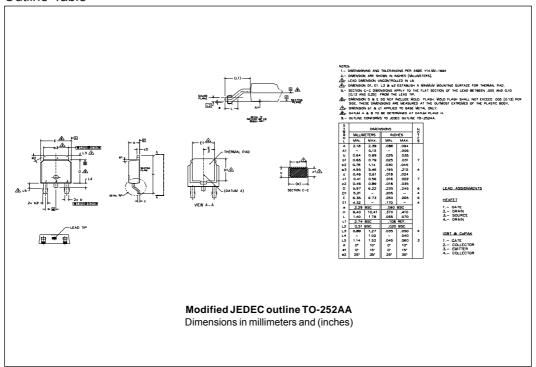


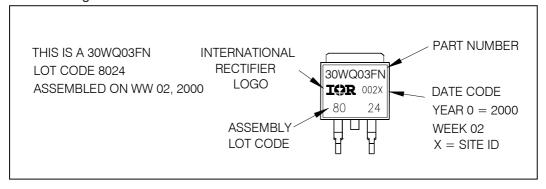
Fig. 7 - Maximum Non-Repetitive Surge Current

(2) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$; $Pd = Forward Power Loss = I_{F(AV)} \times V_{FM} @ (I_{F(AV)}/D) \text{ (see Fig. 6)}$; $Pd_{REV} = Inverse Power Loss = V_{R1} \times I_R (1-D)$; $I_R @ V_{R1} = 80\% \text{ rated } V_R$

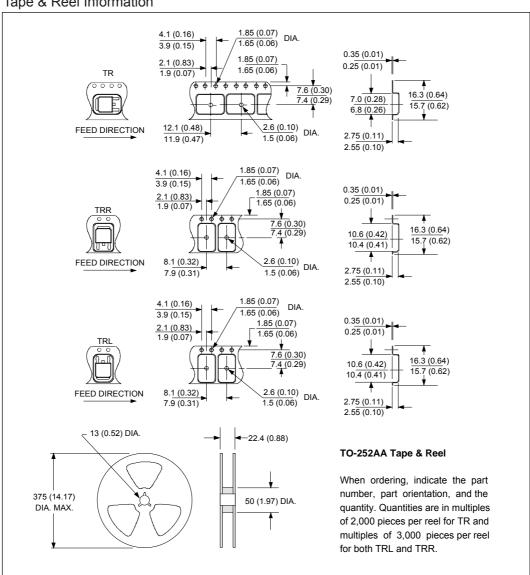
Outline Table



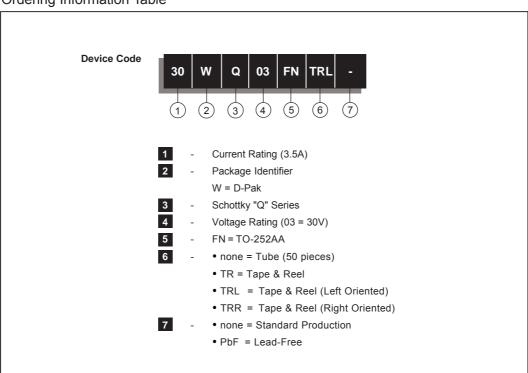
Part Marking Information



Tape & Reel Information



Ordering Information Table



Data and specifications subject to change without notice. This product has been designed and qualified for AEC Q101 Level.

Qualification Standards can be found on IR's Web site.



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Vishay

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